



## Thyristor/Diode and Thyristor/Thyristor (ADD-A-PAK™ Generation 5 Power Modules), 27 A

**ADD-A-PAK™****PRODUCT SUMMARY**

$I_{T(AV)}$ or $I_{F(AV)}$	27 A
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**MECHANICAL DESCRIPTION**

The Generation 5 of ADD-A-PAK™ modules combine the excellent thermal performance obtained by the usage of Direct Bonded Copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid copper baseplate at the bottom side of the device. The Cu baseplate allows an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improved thermal spread. The Generation 5 of AAP modules is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other Vishay HPP modules.

**FEATURES**

- High voltage
- Industrial standard package
- Thick copper baseplate
- UL E78996 approved
- 3500 V<sub>RMS</sub> isolating voltage
- Totally lead (Pb)-free
- Designed and qualified for industrial level

**RoHS**  
COMPLIANT**BENEFITS**

- Up to 1600 V
- Fully compatible TO-240AA
- High surge capability
- Easy mounting on heatsink
- Al<sub>2</sub>O<sub>3</sub> DBC insulator
- Heatsink grounded

**ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery chargers.

**MAJOR RATINGS AND CHARACTERISTICS**

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{T(AV)}$ or $I_{F(AV)}$	85 °C	27	A
$I_{O(RMS)}$	As AC switch	60	
$I_{TSM}$ , $I_{FSM}$	50 Hz	400	
	60 Hz	420	A <sup>2</sup> s
$I^2t$	50 Hz	800	
	60 Hz	730	A <sup>2</sup> √s
$I^2\sqrt{t}$		8000	
$V_{RRM}$	Range	400 to 1600	V
$T_{Stg}$		- 40 to 125	°C
$T_J$			

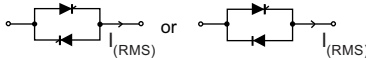
# VSK.26..PbF Series



Vishay High Power Products Thyristor/Diode and Thyristor/Thyristor  
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## ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I <sub>RRM</sub> , I <sub>DRM</sub> AT 125 °C mA
VSK.26	04	400	500	400	15
	06	600	700	600	
	08	800	900	800	
	10	1000	1100	1000	
	12	1200	1300	1200	
	14	1400	1500	1400	
	16	1600	1700	1600	

ON-STATE CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average on-state current (thyristors)	I <sub>T(AV)</sub>	180° conduction, half sine wave, T <sub>C</sub> = 85 °C			27	A	
Maximum average forward current (diodes)	I <sub>F(AV)</sub>						
Maximum continuous RMS on-state current as AC switch	I <sub>O(RMS)</sub>				60		
Maximum peak, one-cycle non-repetitive on-state or forward current	I <sub>TSM</sub> or I <sub>FSM</sub>	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	400		
		t = 8.3 ms	No voltage reapplied		420		
		t = 10 ms	100 % V <sub>RRM</sub> reapplied		335		
		t = 8.3 ms	100 % V <sub>RRM</sub> reapplied		350		
		t = 10 ms	T <sub>J</sub> = 25 °C, no voltage reapplied				470
		t = 8.3 ms					490
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	t = 10 ms	No voltage reapplied	Initial T <sub>J</sub> = T <sub>J</sub> maximum	800	A <sup>2</sup> s	
		t = 8.3 ms	No voltage reapplied		730		
		t = 10 ms	100 % V <sub>RRM</sub> reapplied		560		
		t = 8.3 ms	100 % V <sub>RRM</sub> reapplied		510		
		t = 10 ms	T <sub>J</sub> = 25 °C, no voltage reapplied				1100
		t = 8.3 ms					1000
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t <sup>(1)</sup>	t = 0.1 to 10 ms, no voltage reapplied			8000	A <sup>2</sup> √s	
Maximum value or threshold voltage	V <sub>T(TO)</sub> <sup>(2)</sup>	Low level <sup>(3)</sup>	T <sub>J</sub> = T <sub>J</sub> maximum		0.92	V	
		High level <sup>(4)</sup>			0.95		
Maximum value of on-state slope resistance	r <sub>t</sub> <sup>(2)</sup>	Low level <sup>(3)</sup>	T <sub>J</sub> = T <sub>J</sub> maximum		12.11	mΩ	
		High level <sup>(4)</sup>			11.82		
Maximum peak on-state or forward voltage	V <sub>TM</sub>	I <sub>TM</sub> = π x I <sub>T(AV)</sub>	T <sub>J</sub> = 25 °C		1.95	V	
	V <sub>FM</sub>	I <sub>FM</sub> = π x I <sub>F(AV)</sub>					
Maximum non-repetitive rate of rise of turned on current	di/dt	T <sub>J</sub> = 25 °C, from 0.67 V <sub>DRM</sub> , I <sub>TM</sub> = π x I <sub>T(AV)</sub> , I <sub>g</sub> = 500 mA, t <sub>r</sub> < 0.5 μs, t <sub>p</sub> > 6 μs			150	A/μs	
Maximum holding current	I <sub>H</sub>	T <sub>J</sub> = 25 °C, anode supply = 6 V, resistive load, gate open circuit			200	mA	
Maximum latching current	I <sub>L</sub>	T <sub>J</sub> = 25 °C, anode supply = 6 V, resistive load			400		

### Notes

(1) I<sup>2</sup>t for time t<sub>x</sub> = I<sup>2</sup>√t × √t<sub>x</sub>

(2) Average power = V<sub>T(TO)</sub> × I<sub>T(AV)</sub> + r<sub>t</sub> × (I<sub>T(RMS)</sub>)<sup>2</sup>

(3) 16.7 % × π × I<sub>AV</sub> < I < π × I<sub>AV</sub>

(4) I > π × I<sub>AV</sub>



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TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P <sub>GM</sub>			10	W
Maximum average gate power	P <sub>G(AV)</sub>			2.5	
Maximum peak gate current	I <sub>GM</sub>			2.5	A
Maximum peak negative gate voltage	- V <sub>GM</sub>			10	V
Maximum gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Anode supply = 6 V resistive load	4.0	
		T <sub>J</sub> = 25 °C		2.5	
		T <sub>J</sub> = 125 °C		1.7	
Maximum gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Anode supply = 6 V resistive load	270	mA
		T <sub>J</sub> = 25 °C		150	
		T <sub>J</sub> = 125 °C		80	
Maximum gate voltage that will not trigger	V <sub>GD</sub>	T <sub>J</sub> = 125 °C, rated V <sub>DRM</sub> applied		0.25	V
Maximum gate current that will not trigger	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, rated V <sub>DRM</sub> applied		6	mA

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse and off-state leakage current at $V_{RRM}$ , $V_{DRM}$	$I_{RRM}$ , $I_{DRM}$	$T_J = 125\text{ }^{\circ}\text{C}$ , gate open circuit	15	mA
RMS insulation voltage	$V_{INS}$	50 Hz, circuit to base, all terminals shorted	2500 (1 min) 3500 (1 s)	V
Maximum critical rate of rise of off-state voltage	$dV/dt^{(1)}$	$T_J = 125\text{ }^{\circ}\text{C}$ , linear to 0.67 $V_{DRM}$	500	V/ $\mu$ s

### Note

(1) Available with  $dV/dt = 1000\text{ V/ms}$ , to complete code add S90 i.e. VSKT26/16AS90

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Junction operating and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 125	°C
Maximum internal thermal resistance, junction to case per module		R <sub>thJC</sub>	DC operation	0.31	K/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	5	Nm
	busbar			3	
Approximate weight				110	g
				4	oz.
Case style			JEDEC	TO-240AA	

ΔR CONDUCTION PER JUNCTION											
DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VSK.26	0.23	0.27	0.34	0.48	0.73	0.17	0.28	0.36	0.49	0.73	°C/W

### Note

- Table shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC

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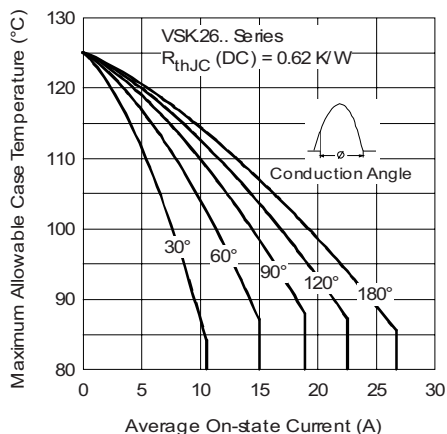


Fig. 1 - Current Ratings Characteristics

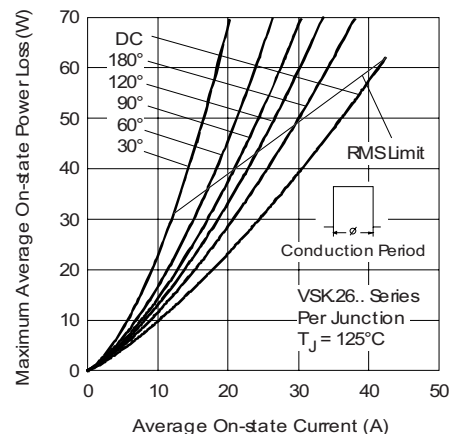


Fig. 4 - On-State Power Loss Characteristics

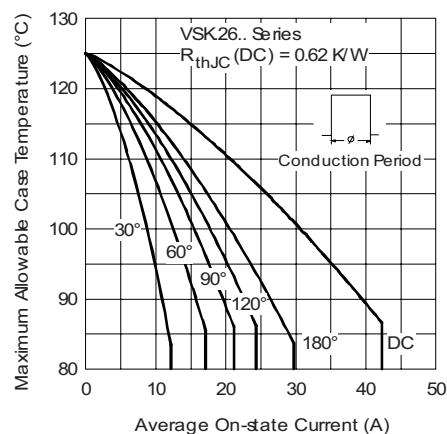


Fig. 2 - Current Ratings Characteristics

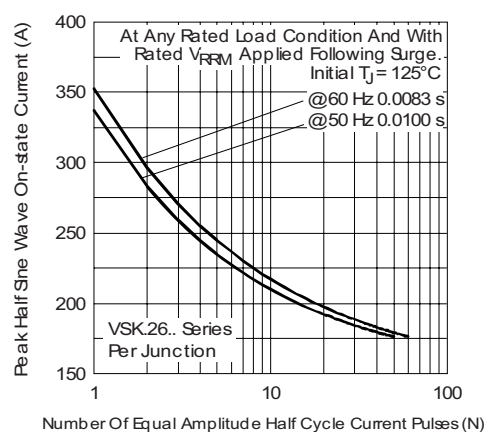


Fig. 5 - Maximum Non-Repetitive Surge Current

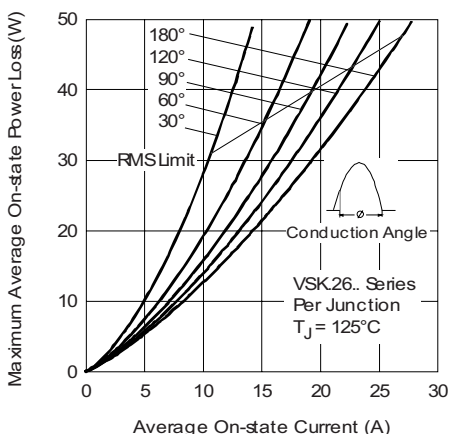


Fig. 3 - On-State Power Loss Characteristics

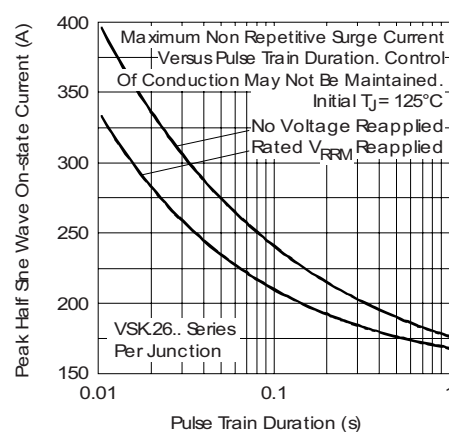


Fig. 6 - Maximum Non-Repetitive Surge Current



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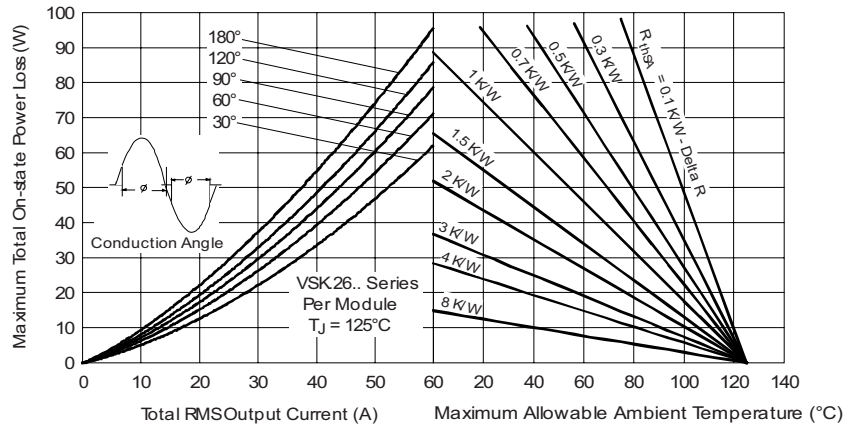


Fig. 7 - On-State Power Loss Characteristics

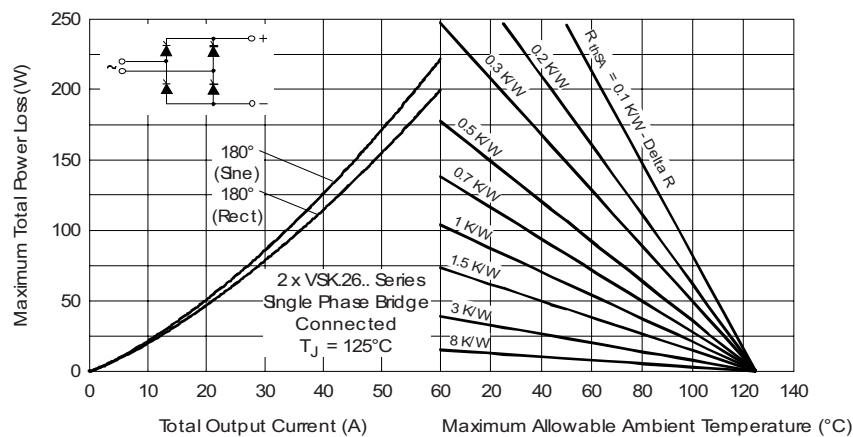


Fig. 8 - On-State Power Loss Characteristics

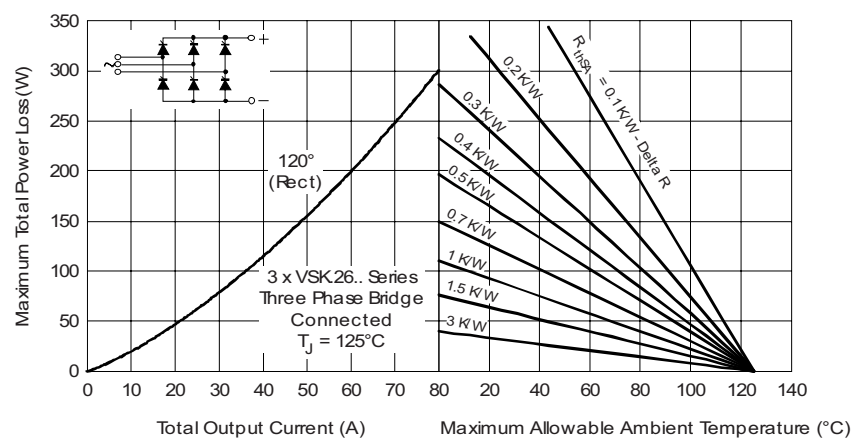


Fig. 9 - On-State Power Loss Characteristics

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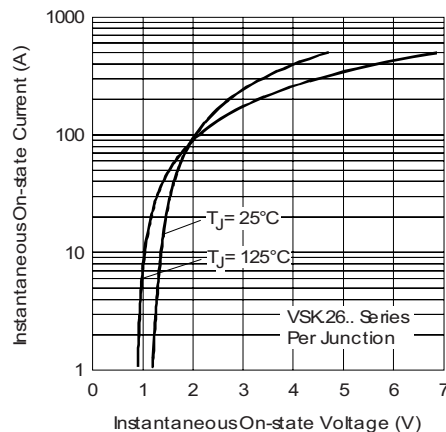


Fig. 10 - On-State Voltage Drop Characteristics

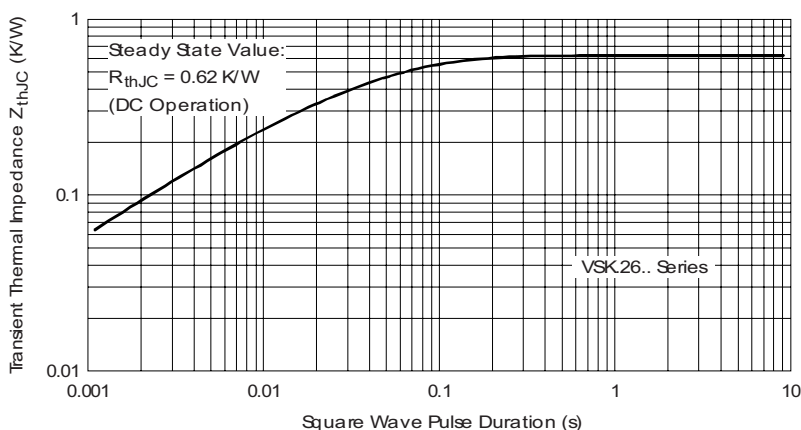


Fig. 11 - Thermal Impedance  $Z_{thJC}$  Characteristics

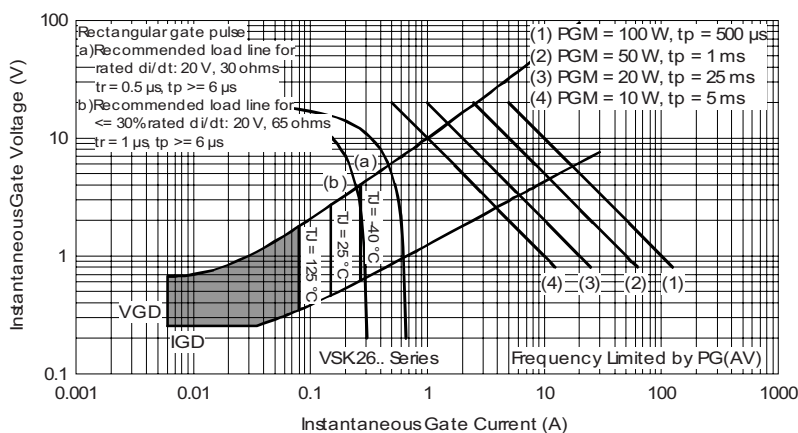


Fig. 12 - Gate Characteristics



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### ORDERING INFORMATION TABLE

Device code	VSK	T	26	/	16	S90	P
	1	2	3		4	5	6

- 1** - Module type
- 2** - Circuit configuration (see end of datasheet)
- 3** - Current code <sup>(1)</sup>
- 4** - Voltage code (see Voltage Ratings table)
- 5** - dV/dt code: S90 = dV/dt 1000 V/μs  
No letter = dV/dt 500 V/μs
- 6** - P = Lead (Pb)-free

<sup>(1)</sup> Available with no auxiliary cathode

(for details see dimensions - link at the end of datasheet)

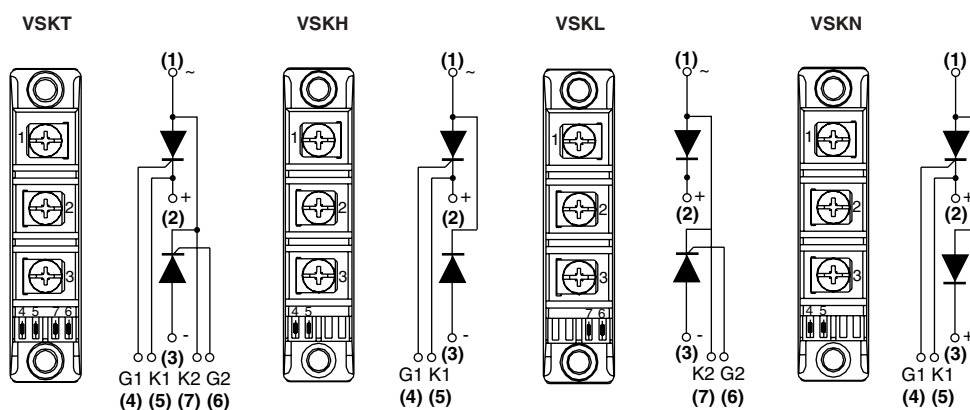
To specify change: 26 to 27

e.g.: VSKT27/16P etc.

#### Note

- To order the optional hardware go to [www.vishay.com/doc?95172](http://www.vishay.com/doc?95172)

### CIRCUIT CONFIGURATION



#### LINKS TO RELATED DOCUMENTS

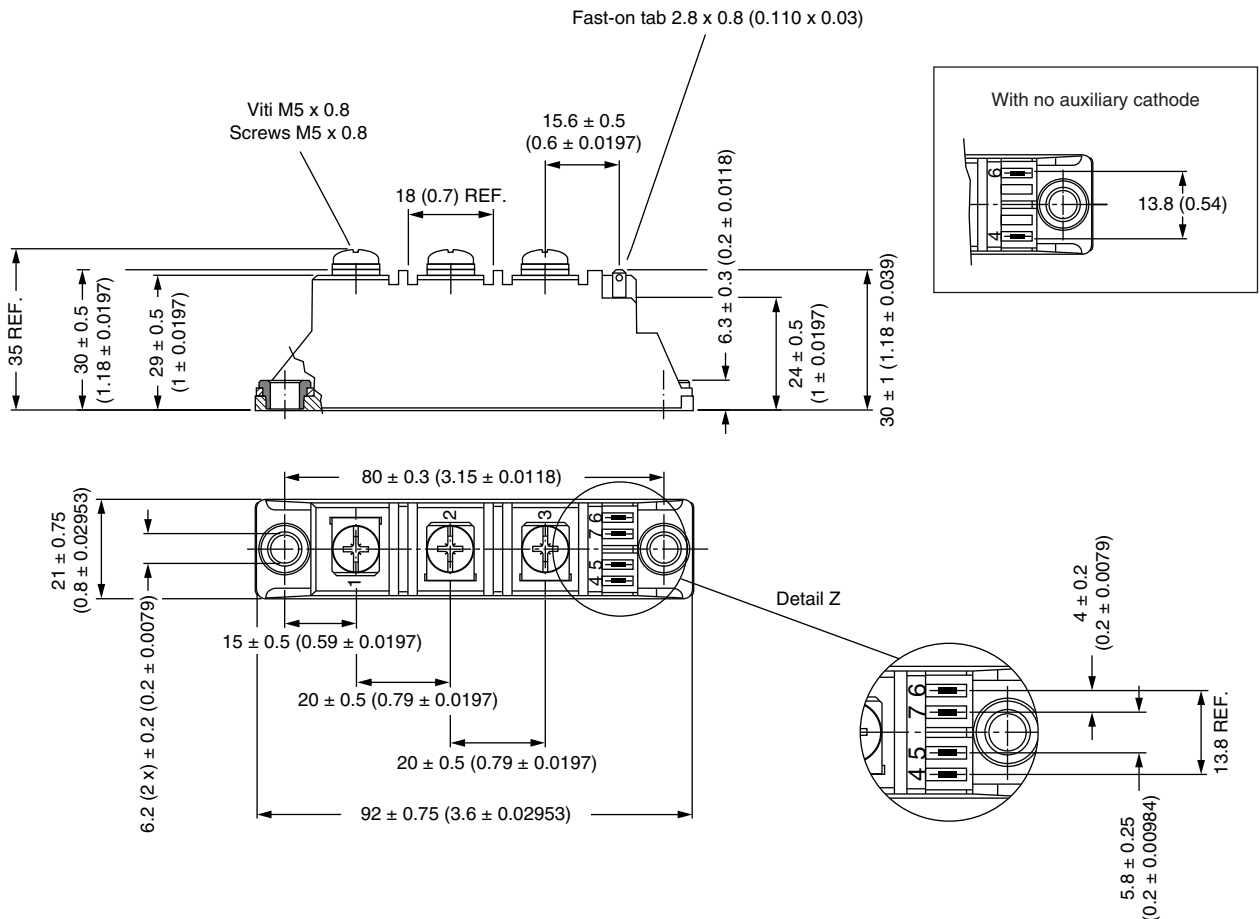
Dimensions

<http://www.vishay.com/doc?95085>



## ADD-A-PAK SCR

**DIMENSIONS** in millimeters (inches)







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